

NVTFS5C658NLWFTAG

NVTFS5C658NLWFTAG Information





Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



NVTFS5C658NLWFTAG Specifications

Manufacturer Part Number	NVTFS5C658NLWFTAG
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-PowerWDFN
Series	Automotive, AEC-Q101
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	60V
Current - Continuous Drain (Id) @ 25°C	109A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2.2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	12nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds	1935pF @ 25V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	114W (Tc)
Rds On (Max) @ Id, Vgs	5 mOhm @ 50A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	8-WDFN (3.3x3.3)
Package / Case	8-PowerWDFN
	Report errors?

NVTFS5C658NLWFTAG Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

NVTFS5C658NLWFTAG Payment Methods



If you have any question about NVTFS5C658NLWFTAG, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com